

## **Description**

The AON6413 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **General Features**

 $V_{DS} = -30VI_{D} = -70A$ 

 $R_{DS(ON)}$  <  $8.8 \text{m}\Omega$   $V_{GS}$ =-10V

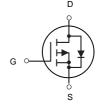
## **Application**

Battery protection

Load switch

Uninterruptible power supply

DFN5X6-8L (PDFN-8(4.9x5.8))



P-Channel MOSFET

## **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
AON6413	DFN5X6-8L(PDFN-8(4.9x5.8))	HXY MOSFET	5000

Absolute Maximum Ratings (Tc=25 ℃ unless otherwise noted)

Symbol	Parameter	Rating	Units	
VDS	Drain-Source Voltage	-30	V	
Vgs	Gate-Source Voltage	±20	V	
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	-70	Α	
I <sub>D</sub> @T <sub>C</sub> =75°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	-40	Α	
Ірм	Pulsed Drain Current <sup>2</sup>	-175	Α	
EAS	Single Pulse Avalanche Energy <sup>3</sup>	31	mJ	
Pp@Tc=25°C	Total Power Dissipation <sup>4</sup>	31.2	W	
Тѕтс	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150	°C	
Rejc	Thermal Resistance Junction-Case <sup>1</sup>	4	°C/W	
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient <sup>1</sup>	61	°C/W	



## ElectricalCharacteristics(T J=25℃ unless otherwise noted)

Parameter		Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Drain-Source Breakdown Voltage		V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_D = -250\mu A$	-30	-	-	V	
Gate-body Leakage current		Igss	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V	-	-	±100	nA	
Zero Gate Voltage Drain	T <sub>J</sub> =25°C		V <sub>DS</sub> = -24V, V <sub>GS</sub> = 0V	-	-	-1	μА	
Current	T <sub>J</sub> =55°C	I <sub>DSS</sub>	$V_{DS} = -24V$ , $V_{GS} = UV$	-	-	-5		
Gate-Threshold Voltage		V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-1.0	-1.6	-2.5	V	
		R <sub>DS(on)</sub>	V <sub>GS</sub> = -10V, I <sub>D</sub> = -12A	-	6	8.8	0	
Drain-Source On-Resistanc	Drain-Source On-Resistance <sup>2</sup>		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -8A	-	9	14	- mΩ	
Forward Transconductance		<b>G</b> fs	V <sub>DS</sub> = -5V, I <sub>D</sub> = -20A	-	28	-	S	
Input Capacitance		C <sub>iss</sub>	V <sub>DS</sub> = -15V, V <sub>GS</sub> =0V, f =1MHz	-	4320	-	pF	
Output Capacitance		Coss		-	529	-		
Reverse Transfer Capacitance		Crss		-	487	-		
Gate Resistance	Gate Resistance		$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$	-	4.0	-	Ω	
Total Gate Charge	Total Gate Charge		V <sub>GS</sub> = -10V, V <sub>DS</sub> = -15V, I <sub>D</sub> = -15A	-	45	-	nC	
Gate-Source Charge		Q <sub>gs</sub>		-	8.5	-		
Gate-Drain Charge		Q <sub>gd</sub>		-	12.8	-		
Turn-On Delay Time		t <sub>d(on)</sub>		-	18.9	-	nS	
Rise Time		t <sub>r</sub>	$V_{GS} = -10V, V_{DD} = -15V,$	-	15.7	-		
Turn-Off Delay Time		t <sub>d(off)</sub>	$R_G = 2.5\Omega$ , $I_D = -15A$	-	64.8	-		
Fall Time		<b>t</b> f		-	36.5	-		
Diode Forward Voltage <sup>2</sup>		V <sub>SD</sub>	I <sub>S</sub> = -1A, V <sub>GS</sub> = 0V	-	-	-1	V	
Continuous Source Current <sup>1,5</sup>		Is	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current	-	-	-70	Α	

#### Note:

- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width  $\leq$  300us , duty cycle  $\leq$  2%
- 3. The EAS data shows Max. rating . The test condition is  $V_{DD}$ = -25V,  $V_{GS}$ = -10V, L= 0.1mH,  $I_{AS}$ = -25A
- 4.The power dissipation is limited by 150°C junction temperature
- 5. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



# **Typical Electrical And Thermal Characteristics (Curves)**

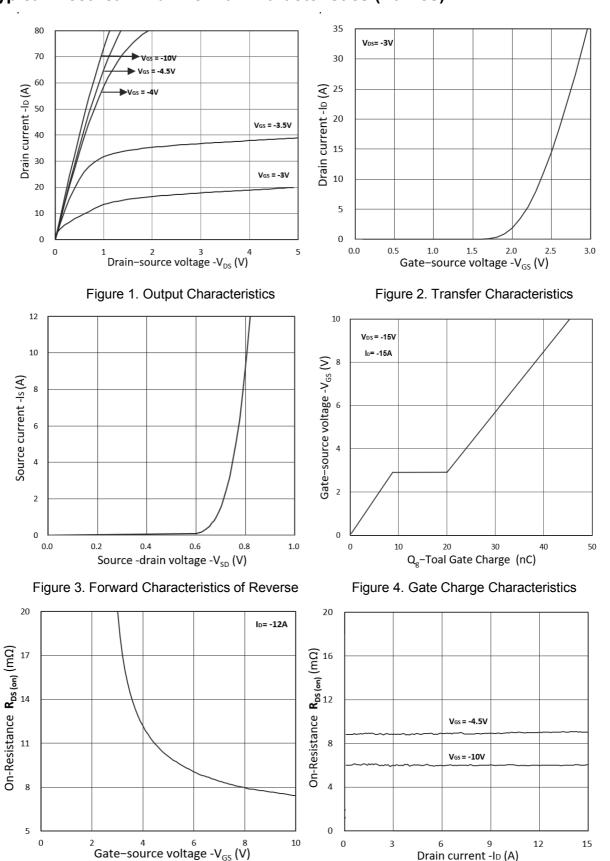


Figure 5. RDS(on) vs. VGS

Figure 6. RDS(on) vs. ID



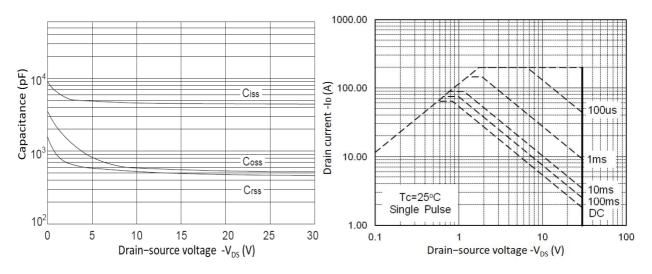


Figure 7. Capacitance Characteristics

Figure 8. Safe Operating Area

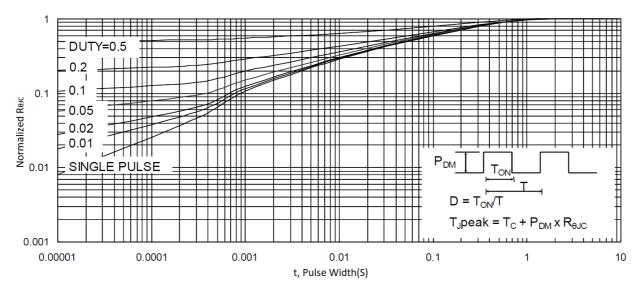


Figure 9. Normalized Maximum Transient Thermal Impedance

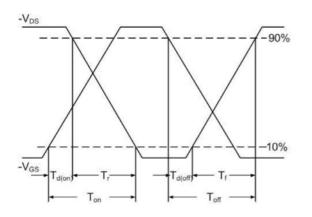


Figure 10. Switching Time Waveform

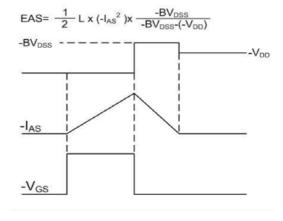


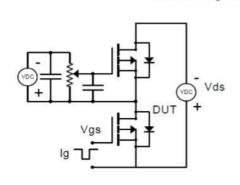
Figure 11. Unclamped Inductive Switching

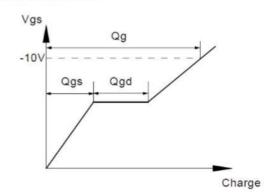
Waveform



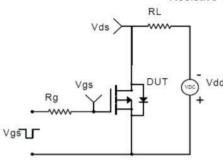
# **Test Circuit**

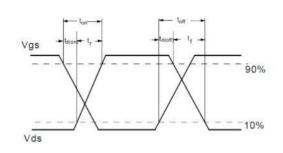
## Gate Charge Test Circuit & Waveform



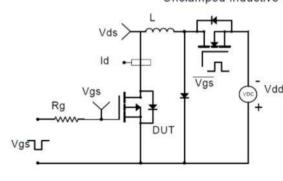


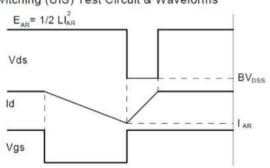
## Resistive Switching Test Circuit & Waveforms



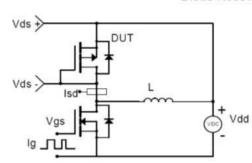


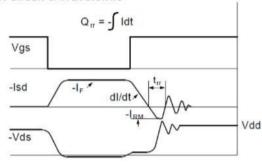
## Unclamped Inductive Switching (UIS) Test Circuit & Waveforms





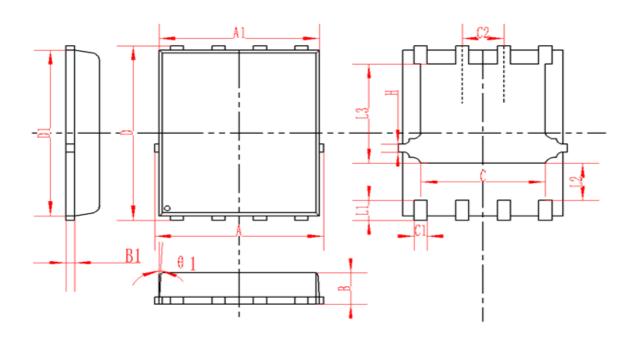
## Diode Recovery Test Circuit & Waveforms







# DFN5X6-8L(PDFN-8(4.9x5.8)) Package Information



SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
А	4.95	5	5.05	0.195	0.197	0.199
A1	4.82	4.9	4.98	0.190	0.193	0.196
D	5.98	6	6.02	0.235	0.236	0.237
D1	5.67	5.75	5.83	0.223	0.226	0.230
В	0.9	0.95	1	0.035	0.037	0.039
B1	0.254REF		0.010REF			
С	3.95	4	4.05	0.156	0.157	0.159
C1	0.35	0.4	0.45	0.014	0.016	0.018
C2		1.27TYP			0.5TYP	
θ1	8°	10°	12°	8°	10°	12°
L1	0.63	0.64	0.65	0.025	0.025	0.026
L2	1.2	1.3	1.4	0.047	0.051	0.055
L3	3.415	3.42	3.425	0.134	0.135	0.135
Н	0.24	0.25	0.26	0.009	0.010	0.010



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